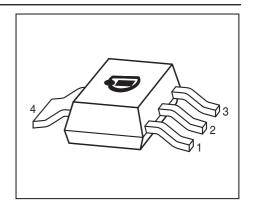


#### **Silicon NPN Transistors**

- For AF driver and output stages
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BDP948, BDP950, BDP954 (PNP)
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101







Туре	Marking	Pin Configuration					Package	
BDP947	BDP947	1=B	2=C	3=E	4=C	-	-	SOT223
BDP949	BDP949	1=B	2=C	3=E	4=C	-	-	SOT223
BDP953	BDP953	1=B	2=C	3=E	4=C	-	-	SOT223

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## **Maximum Ratings**

Parameter	Symbol	Value	Unit	
Collector-emitter voltage	V <sub>CEO</sub>		V	
BDP947		45		
BDP949		60		
BDP953		100		
Collector-base voltage	$V_{\mathrm{CBO}}$			
BDP947		45		
BDP949		60		
BDP953		120		
Emitter-base voltage	V <sub>EBO</sub>	5		
Collector current	I <sub>C</sub>	3	Α	
Peak collector current, $t_p \le 10 \text{ ms}$	I <sub>CM</sub>	5		
Base current	I <sub>B</sub>	200	mA	
Peak base current, $t_p \le 10 \text{ ms}$	I <sub>BM</sub>	500		
Total power dissipation-	P <sub>tot</sub>	5	W	
<i>T</i> <sub>S</sub> ≤ 100 °C				
Junction temperature	$  au_{ m j} $	150	°C	
Storage temperature	$T_{ m stg}$	-65 150		

## **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$	≤ 10	K/W



**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Unit		
		min.	typ.	max.	]
DC Characteristics			•		
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>				V
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0 , BDP947		45	-	-	
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0 , BDP949		60	-	-	
$I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0 , BDP953		100	-	-	
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>				
$I_{\rm C}$ = 100 $\mu$ A, $I_{\rm E}$ = 0 , BDP947		45	-	-	
$I_{\rm C}$ = 100 $\mu{\rm A},I_{\rm E}$ = 0 , BDP949		60	-	-	
$I_{\rm C}$ = 0 , $I_{\rm E}$ = 100 $\mu$ A, BDP953		120	-	-	
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	5	-	-	
$I_{\rm E}$ = 10 $\mu$ A, $I_{\rm C}$ = 0					
Collector-base cutoff current	I <sub>CBO</sub>				μA
$V_{\rm CB} = 45 \text{ V}, I_{\rm E} = 0$		-	-	0.1	
$V_{\mathrm{CB}}$ = 45 V, $I_{\mathrm{E}}$ = 0 , $T_{\mathrm{A}}$ = 150 °C		-	-	20	
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	100	nA
$V_{\text{EB}} = 4 \text{ V}, I_{\text{C}} = 0$					
DC current gain <sup>2)</sup>	h <sub>FE</sub>				-
$I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 5 V		25	-	-	
$I_{\rm C}$ = 500 mA, $V_{\rm CE}$ = 1 V		100	-	475	
$I_{\rm C}$ = 2 A, $V_{\rm CE}$ = 2 V, BDP947, BDP949		50	-	-	
$I_{\rm C}$ = 2 A, $V_{\rm CE}$ = 2 V, BDP953		15	-	-	
Collector-emitter saturation voltage <sup>2)</sup>	V <sub>CEsat</sub>	-	-	0.5	V
$I_{\rm C}$ = 2 A, $I_{\rm B}$ = 0.2 A					
Base emitter saturation voltage <sup>2)</sup>	V <sub>BEsat</sub>	-		1.3	
$I_{\rm C}$ = 2 A, $I_{\rm B}$ = 0.2 A					
AC Characteristics	<u> </u>				
Transition frequency	f <sub>T</sub>	-	100	-	MHz
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 10 V, $f$ = 100 MHz					
Collector-base capacitance	C <sub>cb</sub>	-	25	_	pF
$V_{\rm CB}$ = 10 V, $f$ = 1 MHz					

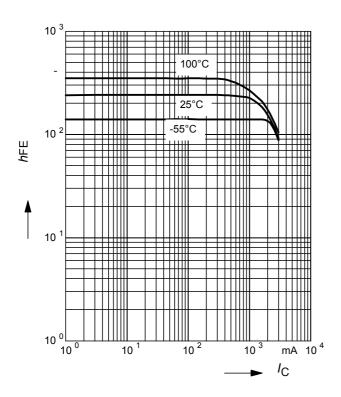
 $<sup>^{1}</sup>$ For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)

<sup>&</sup>lt;sup>2</sup>Pulse test:  $t < 300\mu s$ ; D < 2%



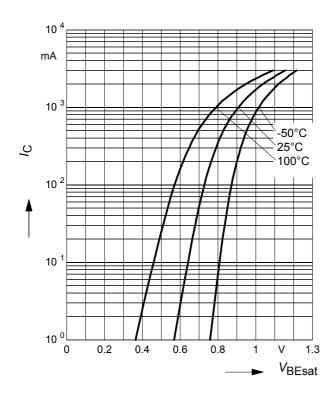
## **DC** current gain $h_{FE} = f(I_C)$

$$V_{CE}$$
 = 2 V



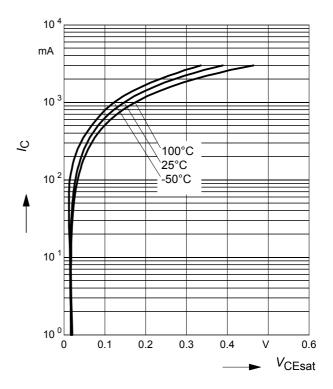
### **Base-emitter saturation voltage**

$$I_{\rm C}$$
 = ( $V_{\rm BEsat}$ ),  $h_{\rm FE}$  = 10



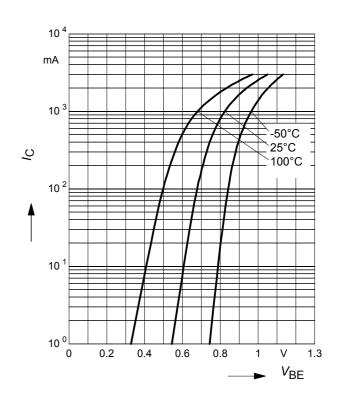
### Collector-emitter saturation voltage

$$I_{\text{C}} = f(V_{\text{CEsat}}), h_{\text{FE}} = 10$$



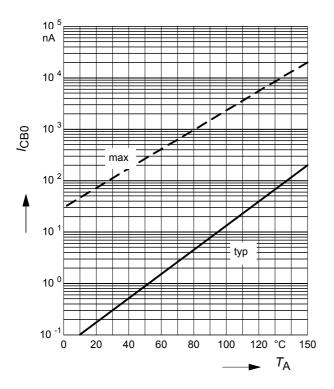
## Collector current $I_{C} = f(V_{BE})$

$$V_{CE} = 2 \text{ V}$$

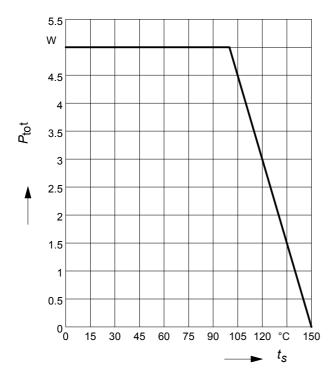




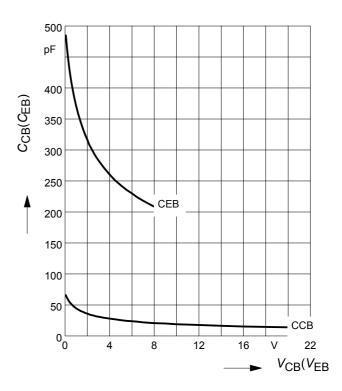
Collector cutoff current  $I_{CBO} = f(T_A)$  $V_{CB} = 45 \text{ V}$ 



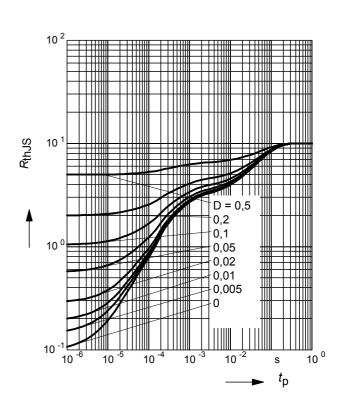
Total power dissipation  $P_{tot} = f(T_S)$ 



Collector-base capacitance  $C_{\text{cb}} = f(V_{\text{CB}})$ Emitter-base capacitance  $C_{\text{eb}} = f(V_{\text{EB}})$ 



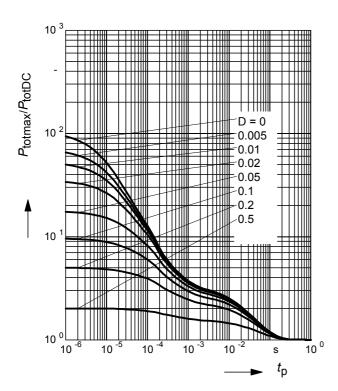
Permissible Pulse Load  $R_{thJS} = f(t_p)$ 





## **Permissible Pulse Load**

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$ 





# Package SOT223 BDP947\_BDP949\_BDP953

# Package Outline 1.6±0.1 $6.5 \pm 0.2$ 0.1 MAX 3±0.1 В $\tilde{\Omega}$ $3.5 \pm 0.2$ 7±0.3 <u>†</u>|2 2.3 $0.7 \pm 0.1$ 0.28 ±0.04 4.6 0...10° ⊕ 0.25 M A = 0.25 M B Foot Print 3.5 1.2 1.1 Marking Layout (Example) **(**infineon Manufacturer 2005, 24 CW Date code (YYWW) 0524 16 BCP52-16 Type code Pin 1 Packing Reel ø180 mm = 1.000 Pieces/Reel Reel ø330 mm = 4.000 Pieces/Reel 0.3 MAX. $\oplus$ 7 7.55 1.75 6.8



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